UNISONIC TECHNOLOGIES CO., LTD

UG10N120

Preliminary

Insulated Gate Bipolar Transistor

35A, 1200V NPT SERIES N-CHANNEL IGBT

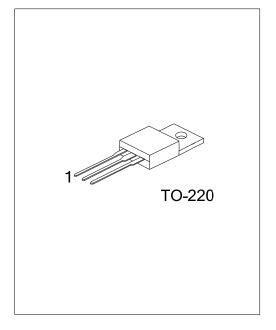
DESCRIPTION

The UTC **UG10N120** is a NPT series N-Channel IGBT, it uses UTC's advanced technology to provide the customers with a minimum on-state resistance, etc.

The UTC **UG10N120** is suitable for AC and DC motor controls, power supplies, and drivers for solenoids, relays and contactors, etc.

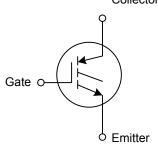
■ FEATURES

- * Low conduction loss
- * Short circuit rating



■ SYMBOL





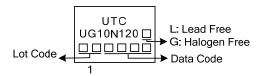
ORDERING INFORMATION

Ordering Number		Deelsese	Pin	Assignn	Doolsing		
Lead Free	Halogen Free	Package	1	2	3	Packing	
UG10N120L-TA3-T	UG10N120G-TA3-T	TO-220	G	С	E	Tube	

Note: Pin Assignment: G: Gate C: Collector E: Emitter

UG10N120L-TA3-T (1)Packing Type (1) T: Tube (2) TA3: TO-220 (3) L: Lead Free, G: Halogen Free

MARKING



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■ ABSOLUTE MAXIMUM RATING (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector to Emitter Voltage		V_{CES}	1200	V
Gate-Emitter Voltage		V_{GES}	±20	V
Gate to Emitter Voltage Pulsed		V_{GEM}	±30	V
Collector Current Continuous	T _C =25°C	- I _C	35	Α
	T _C =110°C		17	Α
Collector Current Pulsed (Note 1)		I _{CM}	80	Α
Power Dissipation Total at T _C = 25°C		P _D	298	W
Power Dissipation Derating T _C > 25°C			2.38	W/°C
Forward Voltage Avalanche Energy (Note 2)		E _{AV}	80	mJ
Short Circuit Withstand Time (Note 3) at V _{GE} =15V		t _{sc}	8	μs
Short Circuit Withstand Time (Note 3) at V _{GE} =12V		t _{SC}	15	μs
Operating Junction Temperature Range		ΤJ	-55~+150	°C
Storage Temperature Range		T _{STG}	-55~+150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Pulse width limited by maximum junction temperature.
- 3. I_{CE} =20A, L=400 μ H, T_{J} =25 $^{\circ}$ C.
- 4. $V_{CE(PK)}$ =840V, T_J =125°C, R_G =10 Ω .

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ_{JC}	0.42	°C/W

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Collector to Emitter Breakdown Voltage	BV _{CES}	I _C =250μA, V _{GE} =0V		1200			V
Emitter to Collector Breakdown Voltage	BV _{ECS}	I _C =10mA, V _{GE} =0V		15			V
			T _C =25°C			250	μΑ
Collector to Emitter Leakage Current	I _{CES}	V _{CE} =1200V	T _C =125°C		150		μΑ
			T _C =150°C			2	mA
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =10A, V _{GE} =15V	T _C =25°C		2.45	2.7	V
			T _C =150°C		3.7	4.2	V
Gate to Emitter Threshold Voltage	$V_{GE(TH)}$	I_C =90 μ A, V_{CE} = V_{GE}		6.0	6.8		V
Gate to Emitter Leakage Current	I _{GES}	V _{GE} =±20V				±250	nA
Switching SOA	SSOA	T_J =150°C, R_G =10 Ω , V_{GE} =15V, L=400 μ H, $V_{CE(PK)}$ =1200V		55			Α
Gate to Emitter Plateau Voltage	V_{GEP}	I _C =10A, V _{CE} =600V			10.4		V
On State Cate Charge	Q _{G(ON)}	I _C =10A, V _{CE} =600V	V _{GE} =15V		100	120	nC
On-State Gate Charge			V _{GE} =20V		130	150	nC
Current Turn-On Delay Time	t _{d(ON)I}	-IGBT and Diode at T_J =25°C -I _{CE} =1A, V_{CE} =30V, V_{GE} =15V, -R _G =10Ω			250		ns
Current Rise Time	t _{rl}				400		ns
Current Turn-Off Delay Time	t _{d(OFF)I}				275		ns
Current Fall Time	t _{fl}				165		ns

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